Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

2.500 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 1.031 inches and 1.063 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

800.0 breakover voltage, dc

Current Rating Per Characteristic:

110.00 amperes drain current

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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